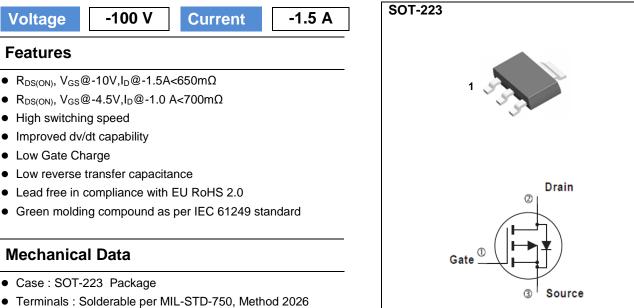
| PAN | ĴΪT |
|-----|-------------------|
| | SEMI CONDUCTOR |

100V P-Channel Enhancement Mode MOSFET



- Approx. Weight : 0.043 ounces, 0.123 grams
- Marking: W2P10A

Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

| | | [| | 1 |
|--|----------------------|----------------------------------|-------------|-------|
| PARAMETE | R | SYMBOL | LIMIT | UNITS |
| Drain-Source Voltage | | V _{DS} | -100 | V |
| Gate-Source Voltage | | V _{GS} | <u>+</u> 20 | V |
| Continuous Drain Current | T _A =25°C | I _D | -1.5 | A |
| | T _A =70°C | | -1.2 | |
| Pulsed Drain Current (Note 1) | | I _{DM} | -6 | А |
| | T _A =25°C | P _D | 3.1 | w |
| Power Dissipation | T _A =70°C | | 2 | |
| Single Pulse Avalanche Energy (Note 5) | | E _{AS} | 0.2 | mJ |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~150 | °C |
| Typical Thermal resistance | | | | |
| - Junction to Ambient (Note 6) | | $R_{	extsf{	heta}JA}$ | 40.3 | °C/W |

• Limited only By Maximum Junction Temperature



Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|---|------|-------|--------------|--------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V,I _D =-250uA | -100 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=-250$ uA | -1.0 | -2.0 | -2.5 | V |
| Drein Course On State Desistance | | V _{GS} =-10V,I _D =-1.5A | - | 500 | 650 | mΩ |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | V _{GS} =-4.5V,I _D =-1.0A | - | 560 | 700 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-80V,V _{GS} =0V | - | - | -1.0 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V,V _{DS} =0V | - | - | <u>+</u> 100 | nA |
| Dynamic (Note 7) | | | | | | |
| Total Gate Charge | Qg | V _{DS} =-50V, I _D =-1.5A, V _{GS} =-10V ^(Note 1,2) | - | 8 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 1.8 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 1.4 | - | |
| Input Capacitance | Ciss | V _{DS} =-15V, V _{GS} =0V, | - | 448 | - | pF |
| Output Capacitance | Coss | | - | 28 | - | |
| Reverse Transfer Capacitance | Crss | f=1.0MHZ | - | 21 | - | |
| Turn-On Delay Time | td _(on) | V_{DS} =-50V,RL=33 Ω , V_{GS} =-10V, R _G =6.2 Ω (Note 1,2) | - | 3.7 | - | |
| Turn-On Rise Time | tr | | - | 25 | - | |
| Turn-Off Delay Time | td _(off) | | - | 21 | - | ns |
| Turn-Off Fall Time | t _f | | - | 22 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source | | | | | 4.5 | |
| Diode Forward Current | I _S | | - | - | -1.5 | -1.5 A |
| Diode Forward Voltage | V _{SD} | I _S =-1A,V _{GS} =0V | - | -0.82 | -1.2 | V |

NOTES :

- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH, I_{AS} =-2A, V_{DD} =-25V, V_{GS} =-10V
- 6. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.



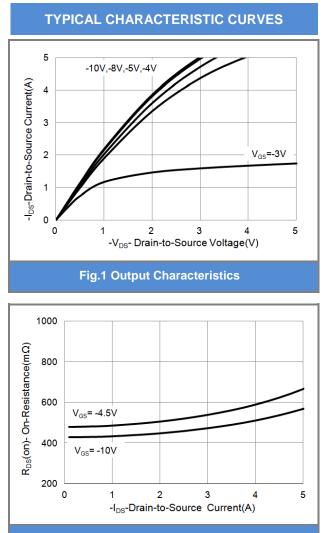
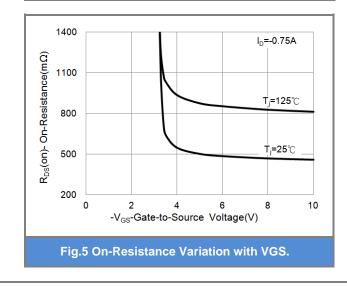


Fig.3 On-Resistance vs. Drain Current



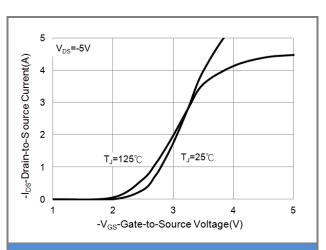


Fig.2 Transfer Characteristics

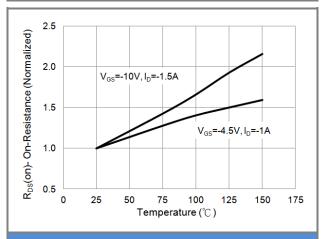
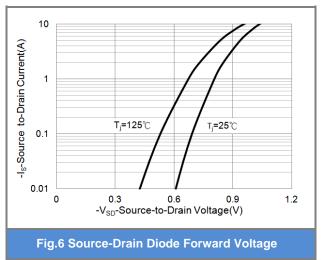
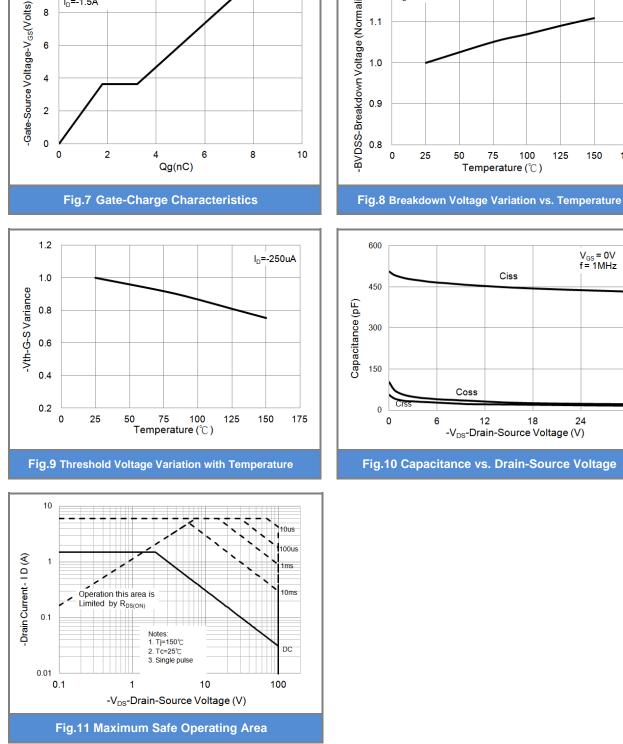


Fig.4 On-Resistance vs. Junction temperature





TYPICAL CHARACTERISTIC CURVES

BVDSS-Breakdown Voltage (Normalized) I_D=-250uA 1.1

1.2

PJW2P10A

V_{DS}=-50V I_D=-1.5A



10

8





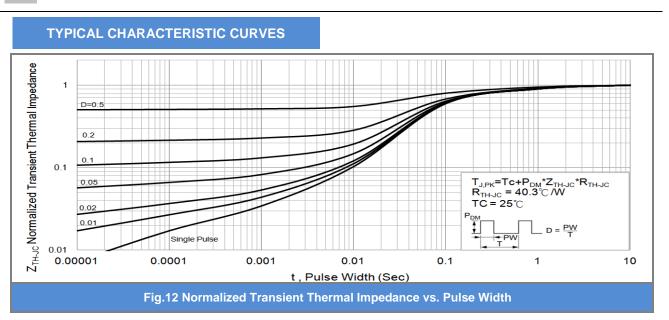
175

30



α,

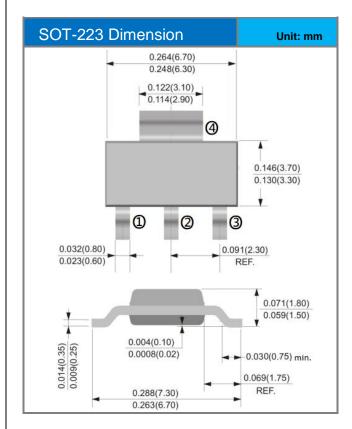
PJW2P10A







Packaging Information



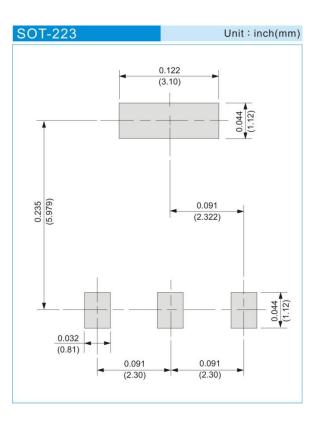




PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type | Marking | Version |
|----------------------|--------------|---------------------|---------|--------------|
| PJW2P10A_R2_00001 | SOT-223 | 2,500pcs / 13" reel | W2P10A | Halogen free |

MOUNTING PAD LAYOUT







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